

**Supplementary File:**

**Phosphine oxide based semiconducting small molecule as an additive and an electron transport layer enables efficient and stable perovskite light emitting devices**

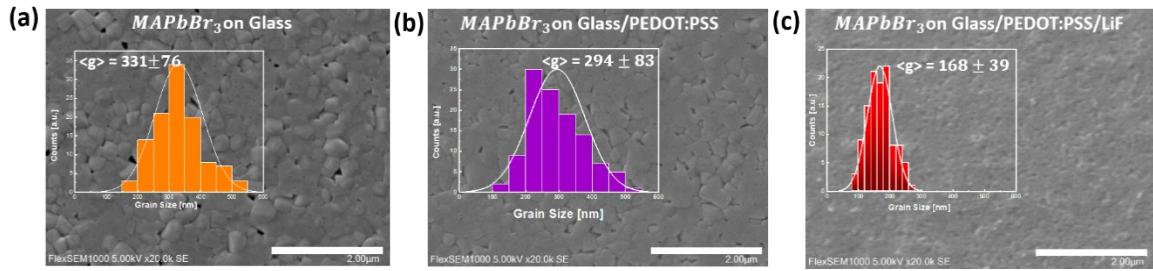
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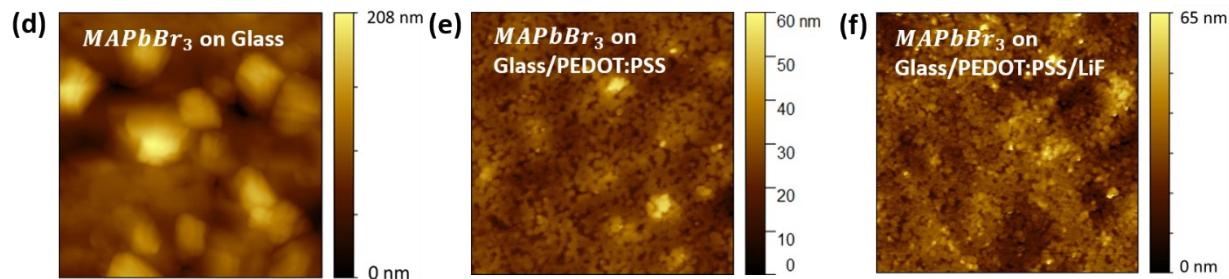
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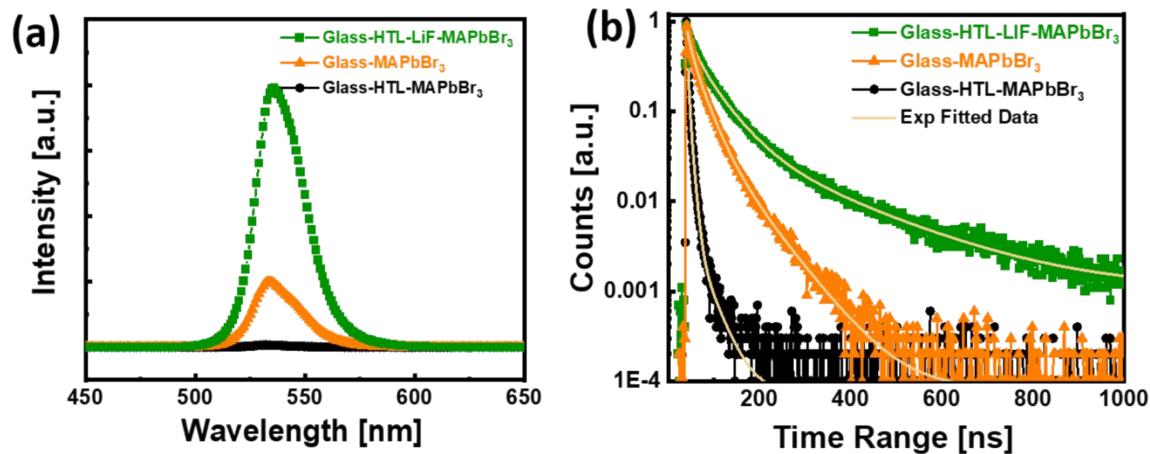
Keywords: Perovskite LED, PO-T2T small molecule additive, Methylammonium lead bromide ( $\text{MAPbBr}_3$ ), Stable PL, Higher EL lifetime stability



**Figure S1.** SEM images [Top row] and AFM images [Bottom Row] of  $\text{MAPbBr}_3$  films on top of Glass,



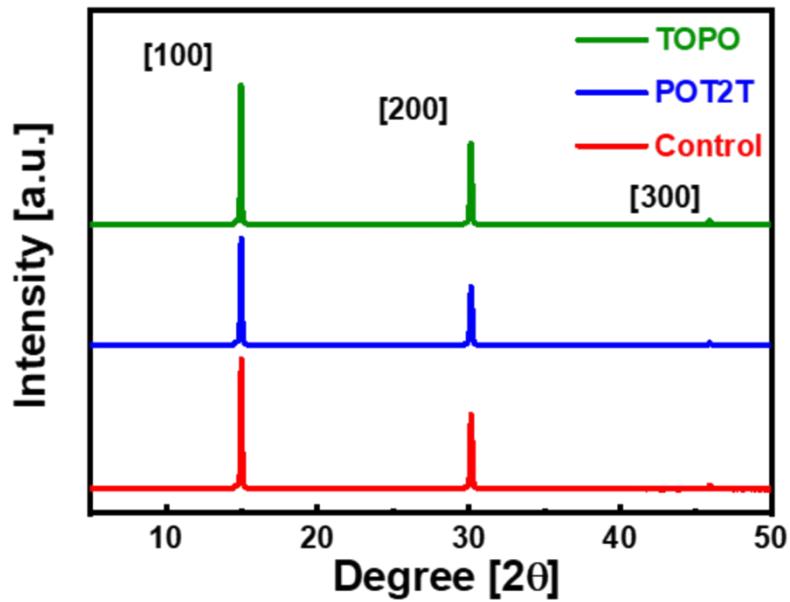
Glass/PEDOT: PSS and Glass/PEDOTPSS/LiF. The scale bar for SEM is 2um and AFM images are of scan size 5 × 5 um



**Figure S2.** (a) Steady state photoluminescence spectra (b) Time resolved photoluminescence spectra of MAPbBr<sub>3</sub> films deposited on Glass, on Glass/PEDOT:PSS and on Glass/PEDOT:PSS/3 nm LiF.

	$\tau_1$ [ns]	$B_1$ [%]	$\tau_2$ [ns]	$B_2$ [%]	$\tau_3$ [ns]	$B_3$ [%]	$\tau_{ave}$ [ns]	$\chi^2$
Glass/ MAPbBr <sub>3</sub>	8.24	11.11	26.47	62.15	67.63	26.74	35.45	0.7850
Glass/PEDOT: PSS/ MAPbBr <sub>3</sub>	2.34	47.71	6.63	48.02	31.86	4.27	5.66	0.6284
Glass/PEDOT: PSS/LiF/ MAPbBr <sub>3</sub>	15.88	12.22	51.93	60.09	194.80	27.70	87.10	0.9513

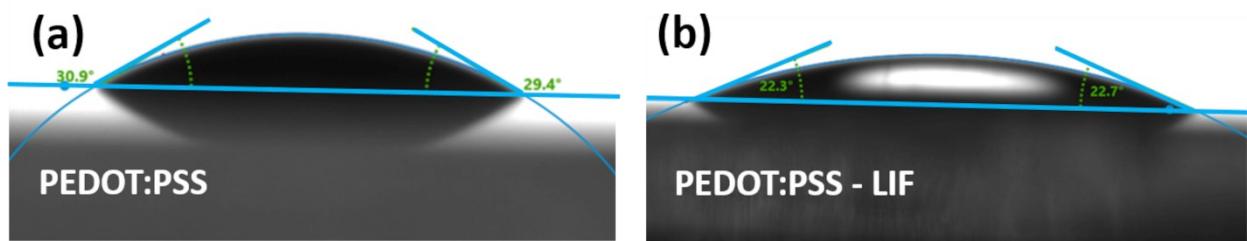
**Table S1.** TRPL decay curve fitting and average lifetime calculated from tri-exponential fit for MAPbBr<sub>3</sub> films on 1) Glass 2) Glass/PEDOT:PSS 3) Glass/PEDOT:PSS/LiF .



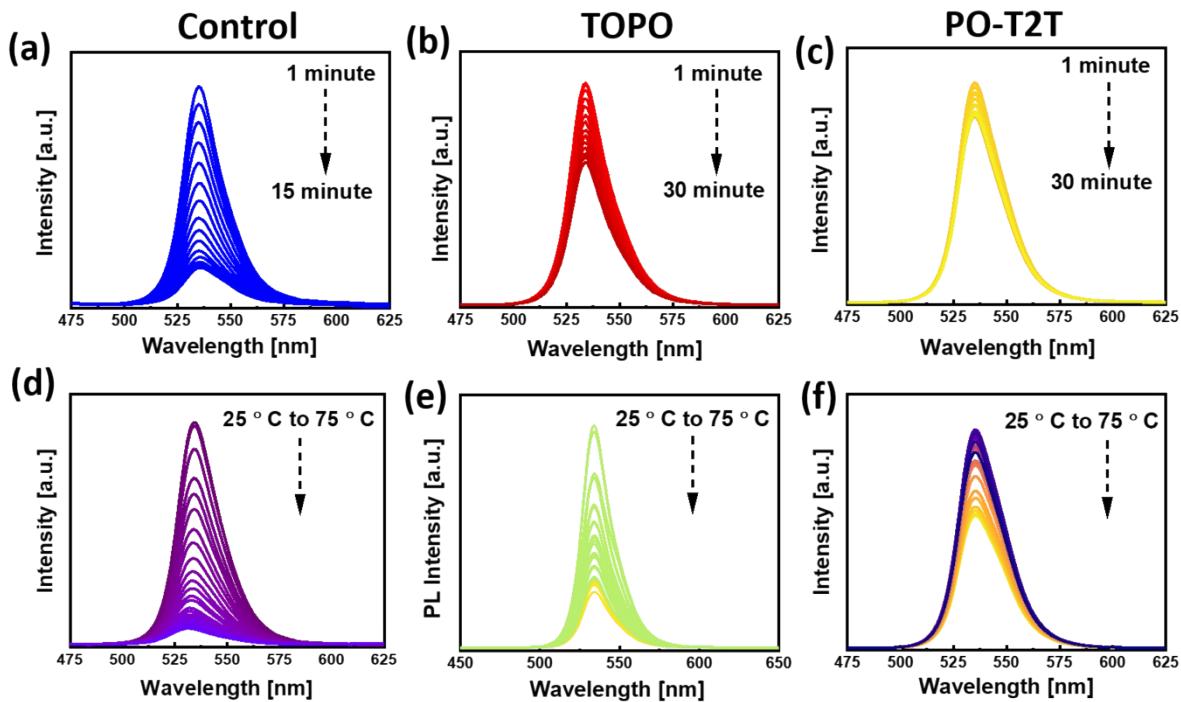
**Figure S3.** XRD spectra of  $\text{MAPbBr}_3$  polycrystalline films with different additives (films made on HTL [Glass/PEDOT:PSS/3 nm LiF]

MAPbBr <sub>3</sub> films made on Glass/PEDOT: PSS/3 nm LiF with below mentioned additive	[hkl]	Position [2θ] (degree)	FWHM (degree)	Lattice Constant (Å)	Intensity (A.U)	Strain
Control (no additive)	[100]	14.96	0.11	5.91	135311	0.054
	[200]	30.14	0.15	5.92	77832	
	[300]	45.90	0.18	5.92	3913	
TOPO	[100]	14.94	0.11	5.92	145579	0.053
	[200]	30.14	0.15	5.92	85020	
	[300]	45.90	0.18	5.92	4595	
PO-T2T	[100]	14.96	0.13	5.91	111167	0.042
	[200]	30.14	0.16	5.92	61762	
	[300]	45.90	0.18	5.92	3224	

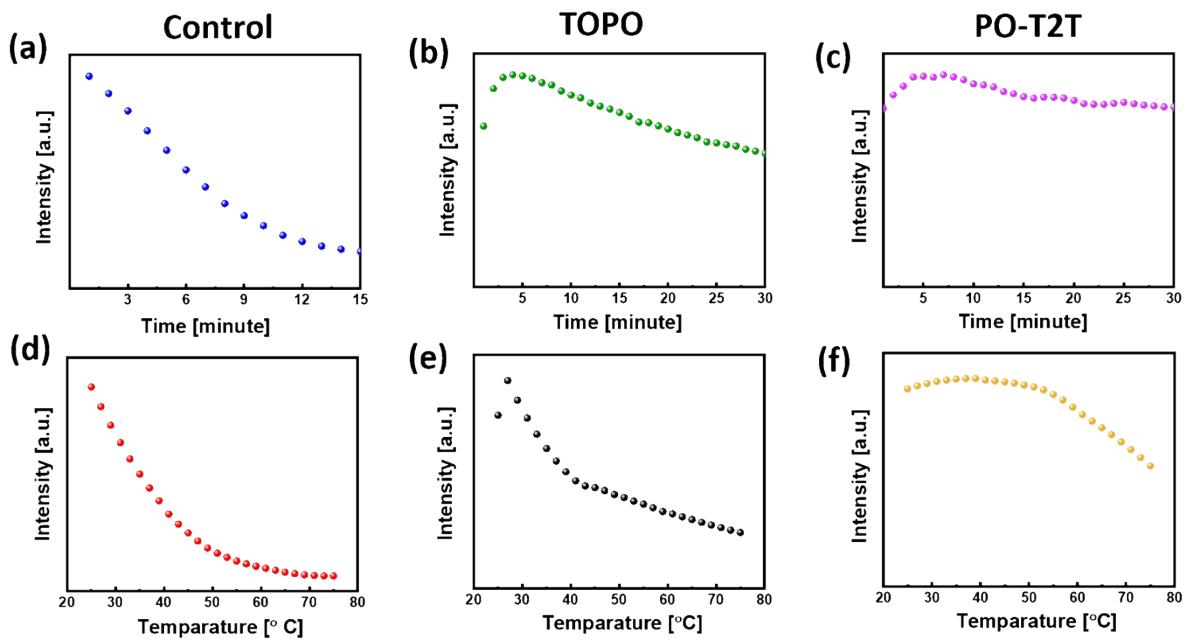
**Table S2.** Summary of XRD measurements on MAPbBr<sub>3</sub> films with different additives



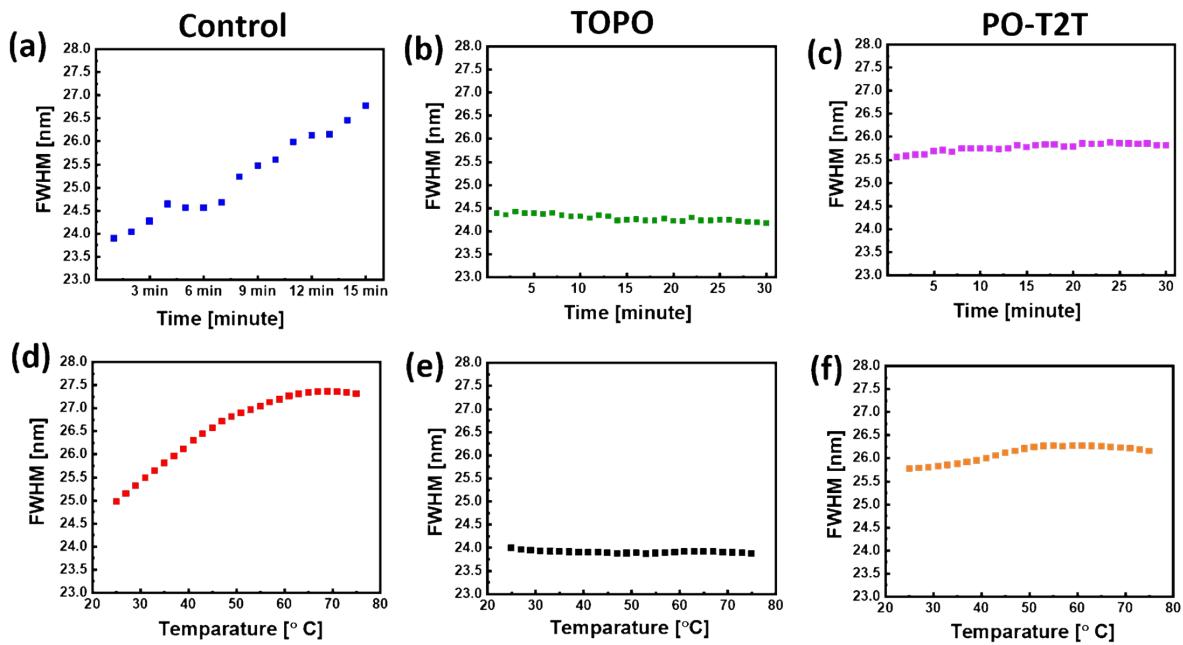
**Figure S4.** Contact angle of water measured (a) On glass/PEDOT:PSS layer (b) On  
glass/PEDOT:PSS/3 nm LiF layer



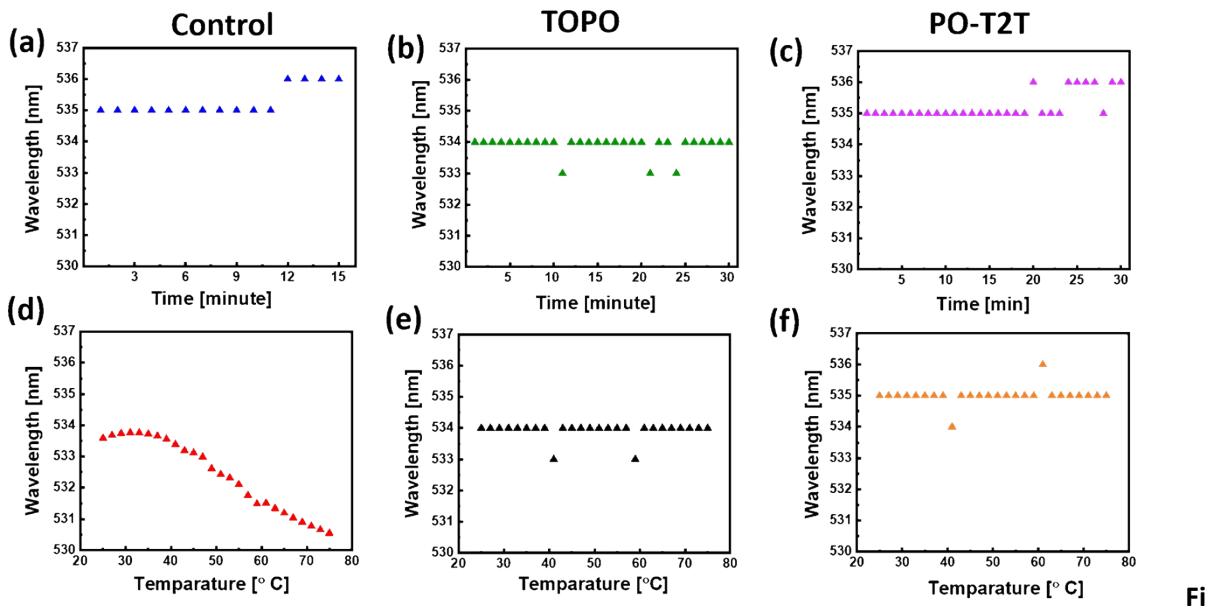
**Figure S5.** PL spectra recorded as a function of time (a-c) and temperature (d-f) for  $\text{MAPbBr}_3$  films with control, TOPO and PO-T2T additives. Data is extracted from 2D PL maps shown in **Figure 5**. For control sample PL spectral intensity decreases by 83 %, for film with TOPO as additive there is decrease in PL spectral intensity by 40 % and for film with PO-T2T as additive the decrease in PL spectral intensity is significantly lower (20 %) as a function of time. Similarly, the decrease in PL Intensity for Control, TOPO as additive and PO-T2T as additive is 93 %, 75 % and 40 % respectively as a function of temperature. For all films we monitored the PL spectral intensity changes for 30 minutes and temperature is varied from room temperature to 75-degree C in 2-degree interval



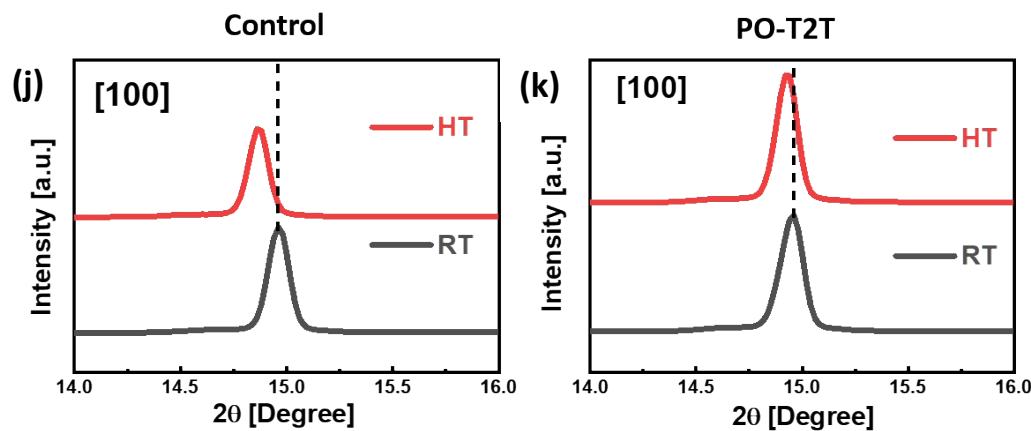
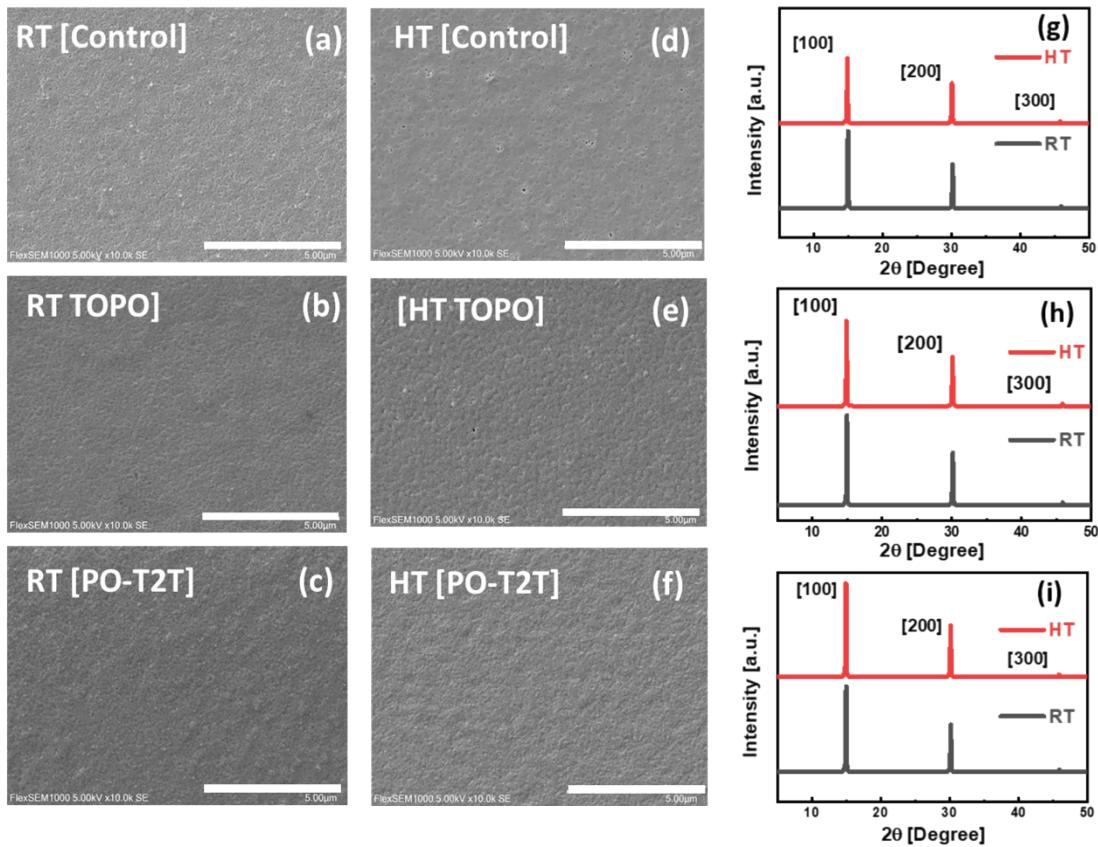
**Figure S6.** Integrated PL spectra as a function of time (a-c) and temperature (d-f) for MAPbBr<sub>3</sub> films with control, TOPO and POT-2T additives. Data is extracted from 2D PL maps shown in **Figure 5**.



**Figure S7.** FWHM as a function of time (a-c) and temperature (d-f) for  $\text{MAPbBr}_3$  films with control, TOPO and PO-T2T additives. Data is extracted from 2D PL maps shown in **Figure 5**.



**Figure S8.** Peak wavelength as a function of time (a-c) and temperature (d-f) for  $\text{MAPbBr}_3$  films with control, TOPO and PO-T2T additives. Data is extracted from 2D PL maps shown in **Figure 5**.

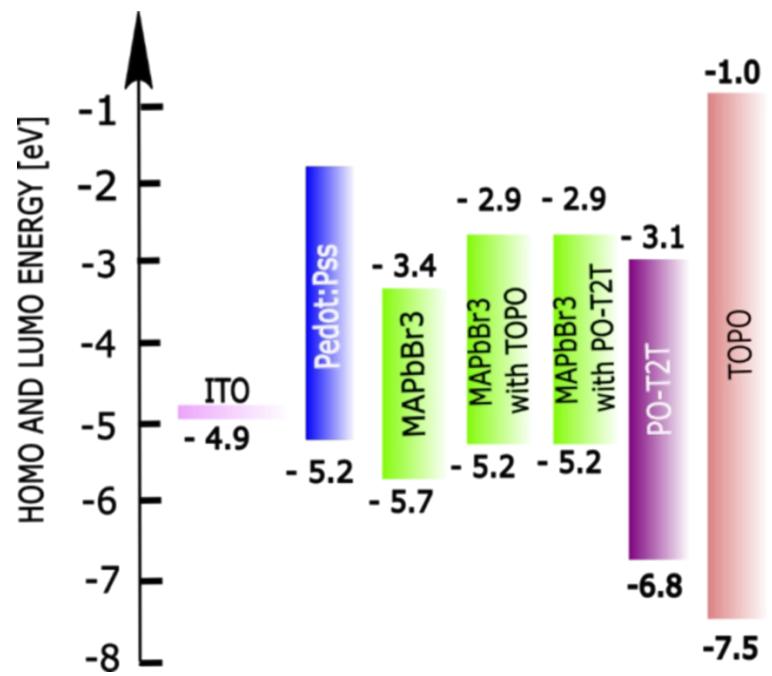


**Figure S9.** SEM images of MAPbBr<sub>3</sub> films at room temperature (a-c) and high temperature (75 deg) (d-f) for control, TOPO and POT-2T additives. XRD spectra were recorded at room and high

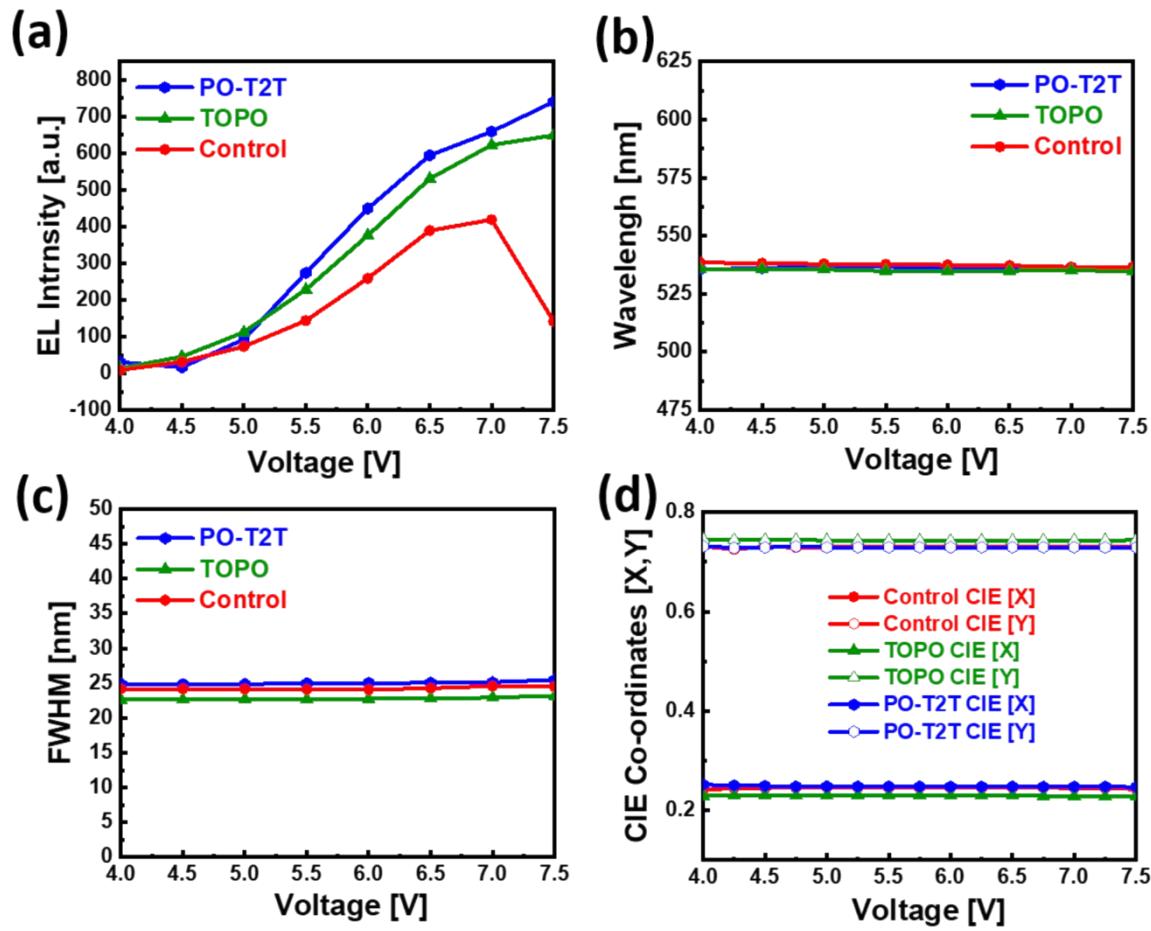
temperature (75 deg) for control (g), TOPO (h) and PO-T2T(i) additives. Enlarged version of XRD spectra on top of HTL for Control and PO-T2T treated films are shown in Figure (j) and (k).

<b>Composition</b>	<b>[hkl]</b>	<b>Position [2<math>\theta</math>] (degree)</b>	<b>Lattice Constant (Å)</b>
Control [RT]	[100]	14.96	5.91
	[200]	30.14	5.92
	[300]	45.90	5.92
PO-T2T [RT]	[100]	14.96	5.91
	[200]	30.14	5.92
	[300]	45.90	5.92
Control [HT]	[100]	14.86	5.95
	[200]	30.06	5.94
	[300]	45.82	5.93
PO-T2T [HT]	[100]	14.92	5.93
	[200]	30.12	5.92
	[300]	45.88	5.92

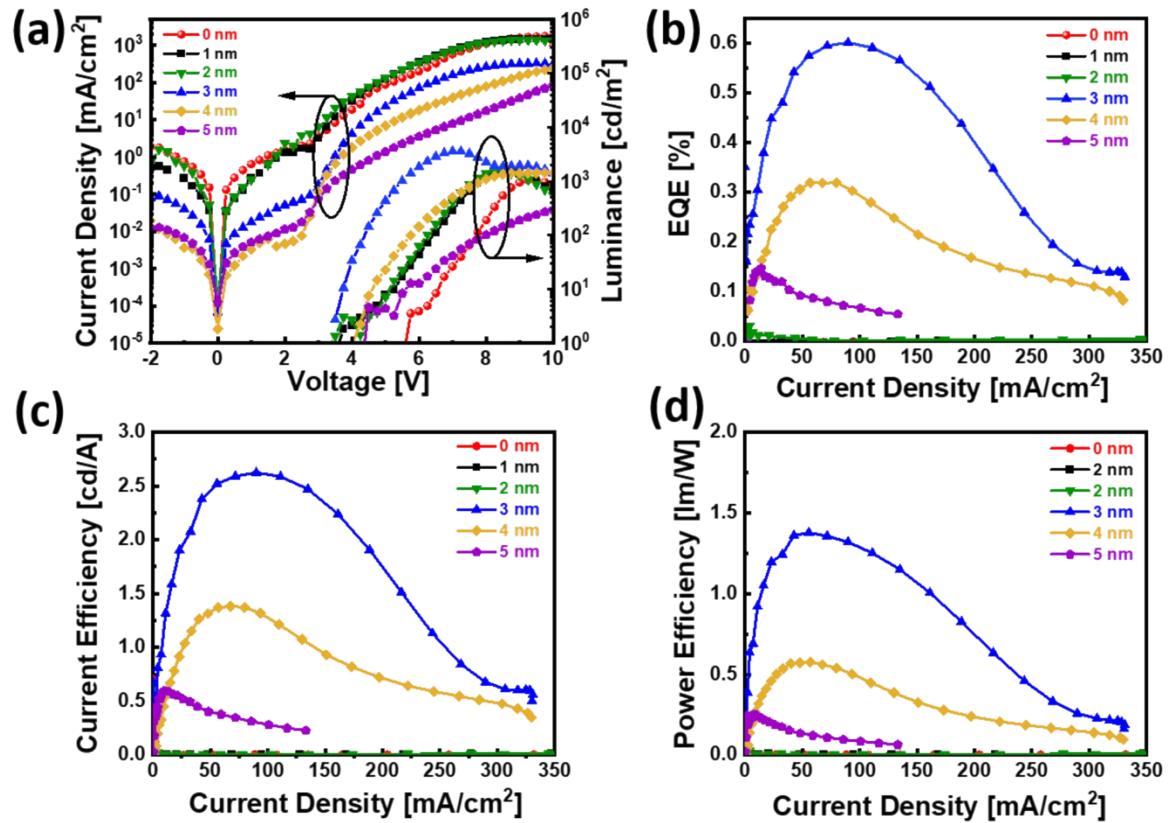
**Table S3:** Summary of XRD measurements on  $MAPbBr_3$  films with different compositions at different temperatures.



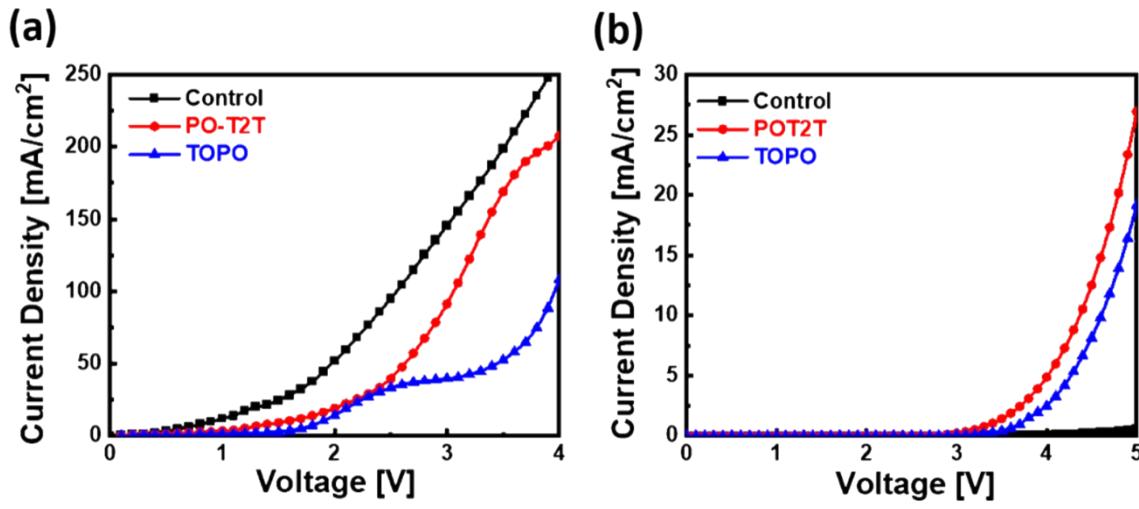
**Figure S10.** Energy level diagram for Pe-LED device and its components



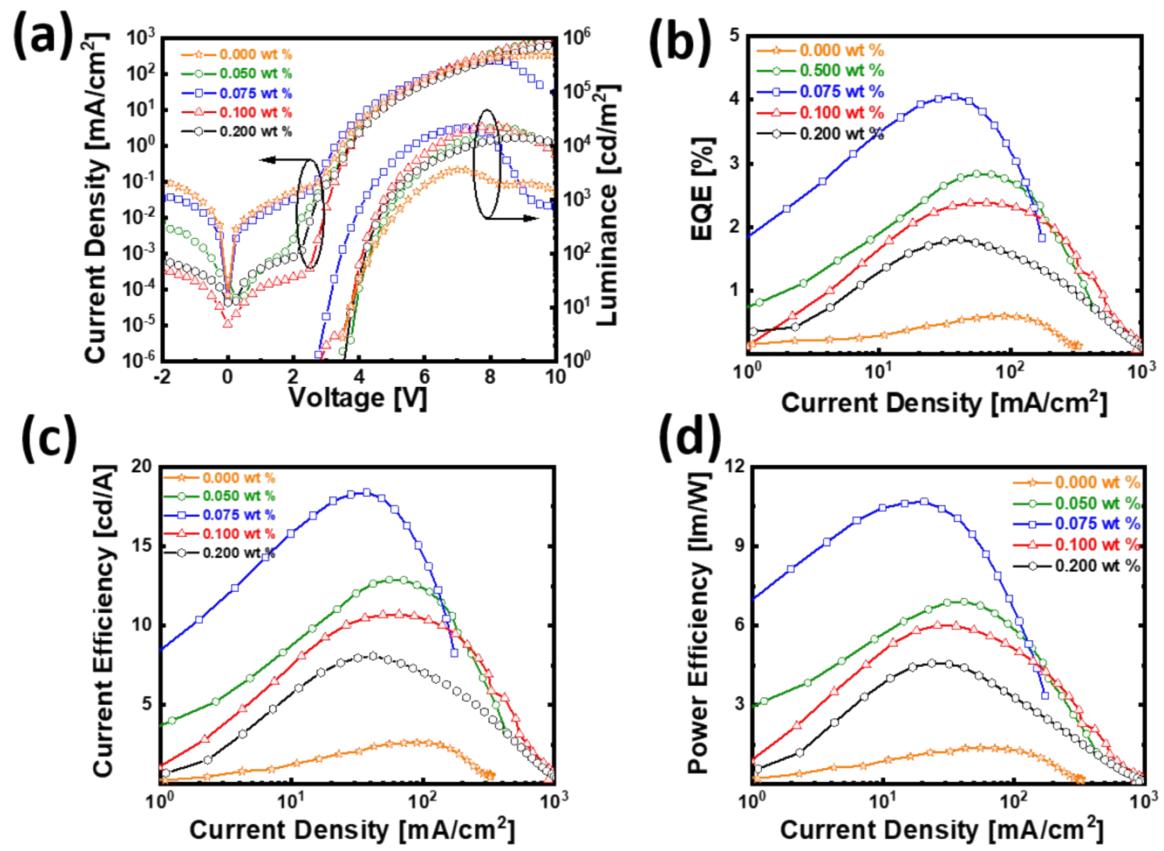
**Figure S11.** (a) EL intensity (from EL Spectrum), (b) Wavelength, (c) FWHM and (d) CIE coordinate (0.2, 0.7) changes plotted as a function of voltage bias for Pe-LED devices made with control, TOPO and PO-T2T additives



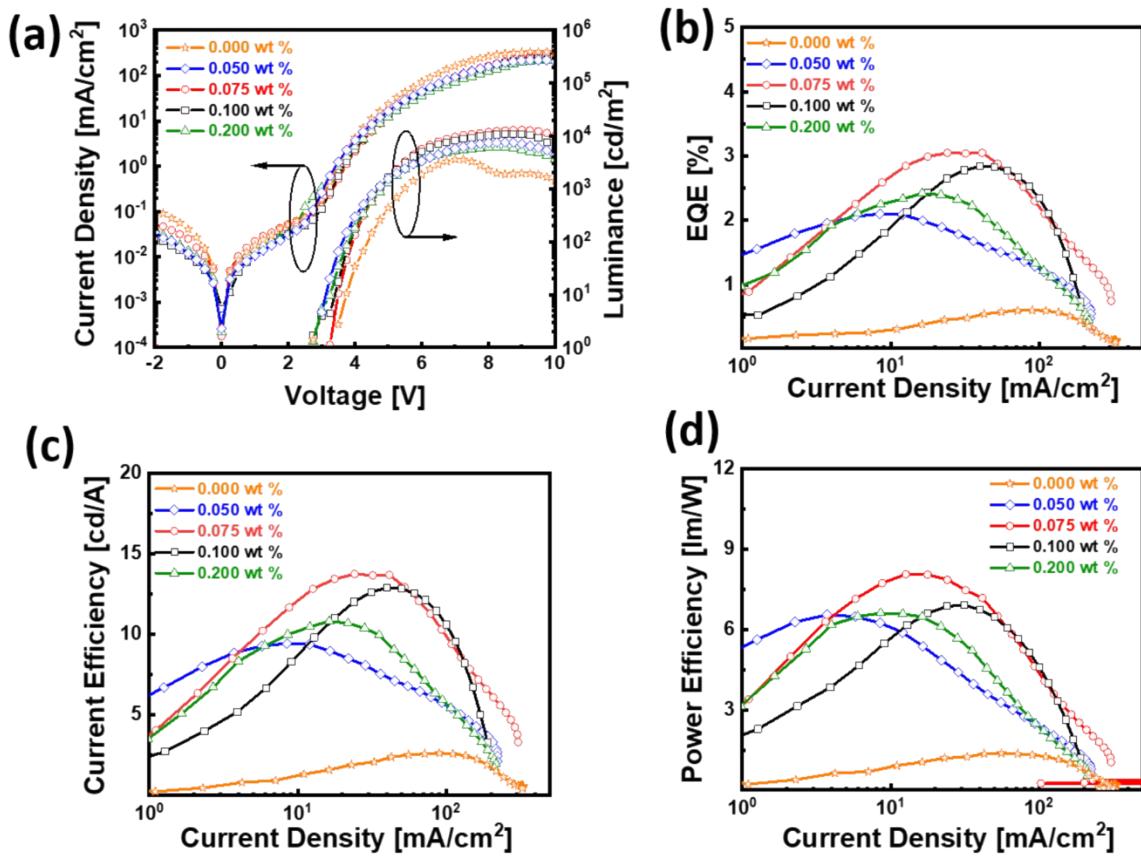
**Figure S12.** LiF layer optimization: Current Density-Voltage-Luminance [J-V-L] characteristics, EQE vs Current Density, Current Efficiency vs Current Density and Power Efficiency vs Current Density of Perovskite LEDs with different LiF layer thickness from 0-5nm.



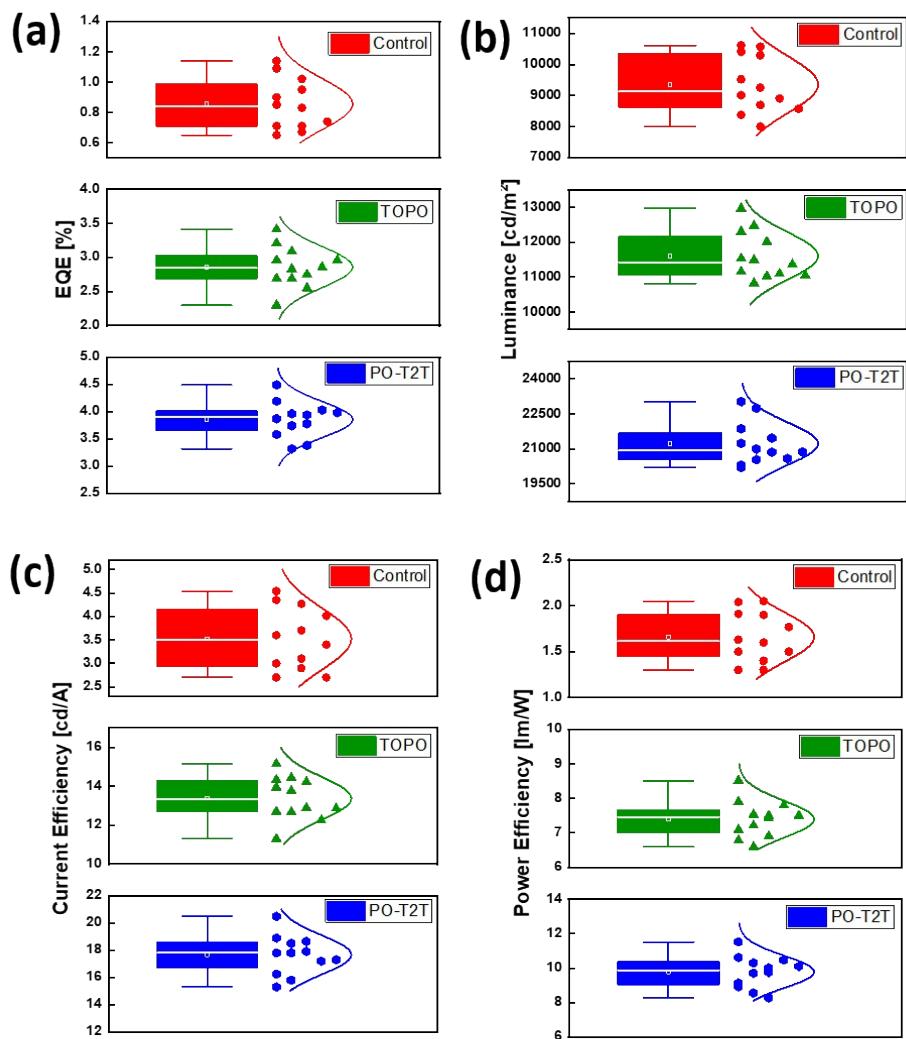
**Figure S13.** Current density-voltage plots for (a) Glass/ITO/PEDOT:PSS:LiF/ MAPbBr<sub>3</sub> with different Additives/LiF/Al (b) Glass/ITO/ MAPbBr<sub>3</sub> with different Additives/TPBi/LiF/Al.



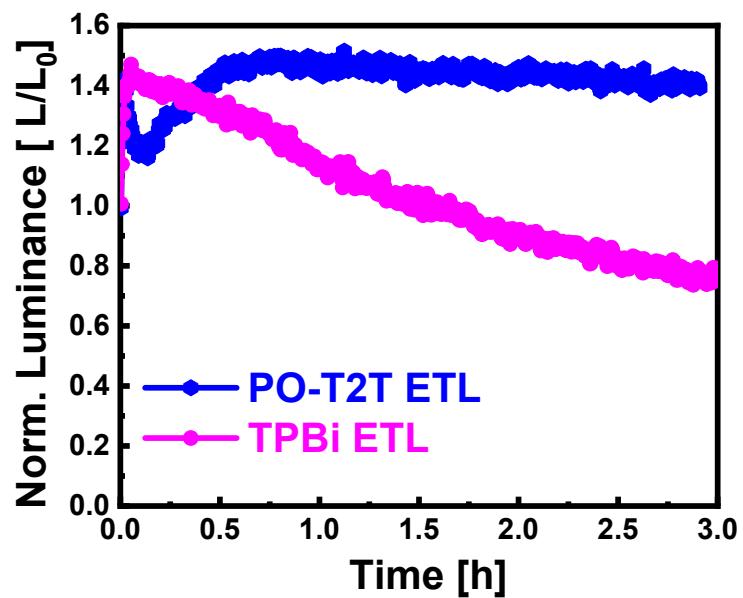
**Figure S14.** Optimization of PO-T2T in anti-solvent treatment for forming  $\text{MAPbBr}_3$  films



**Figure S15.** Optimization of TOPO in anti-solvent treatment for forming  $\text{MAPbBr}_3$  films



**Figure S16:** Histograms for (a) EQE (b) Luminance (c) Current Efficiency and (d) Power Efficiency of 12 Pe-LED devices.



**Figure S17.** Comparison of Pe-LED lifetime with TPBi ETL conventionally used and PO-T2T ETL used in this work. The MAPbBr<sub>3</sub> films had PO-T2T as additive in antisolvent in both cases.

**Table S4:** A literature survey of device performance of 3D Bulk  $\text{MAPbBr}_3$  Perovskite-based LEDs.

Serial Number	Composition of Perovskite	EQE [%]	Current Efficiency [ $\text{mA}/\text{cm}^2$ ]	EL Stability	Reference Number
1.	$\text{MAPbBr}_3$ [3D, Bulk]	8.53	42.9	-	[Ref] <sup>1</sup>
2.	$\text{MAPbBr}_3$ [3D, Bulk]	2.96	14.31	-	[Ref] <sup>2</sup>
3.	$\text{MAPbBr}_3$ [3D, Bulk]	0.78	3.7	-	[Ref] <sup>3</sup>
4.	$\text{MAPbBr}_3$ [3D, Bulk]	-	0.05	-	[Ref] <sup>4</sup>
5.	$\text{MAPbBr}_3$ [3D, Bulk]	-	9.45	$L_{50} \sim 0.31 \text{ hr}$ @ 100 $\text{cd}/\text{m}^2$	[Ref] <sup>5</sup>
6.	$\text{MAPbBr}_3$ [3D, Bulk]	2.36	8.76	$L_{50} \sim 120 \text{ s}$	[Ref] <sup>6</sup>
7.	$\text{MAPbBr}_3$ [3D, Bulk]	0.8	-	-	[Ref] <sup>7</sup>
8.	$\text{MAPbBr}_3$ [3D, Bulk]	0.07	-	$L_{50} \sim 340 \text{ s}$	[Ref] <sup>8</sup>
9.	$\text{MAPbBr}_3$ [3D, Bulk]		13.23	$L_{40} \sim 38 \text{ min}$	[Ref] <sup>9</sup>
10.	$\text{MAPbBr}_3$ [3D, Bulk]	1.03	-	$L_{50} < 100 \text{ s}$	[Ref] <sup>10</sup>
11.	$\text{MAPbBr}_3$ [3D, Bulk]	0.71	-	$L_{50} \sim 55 \text{ min}$ @ 50 $\text{mA}/\text{cm}^2$	[Ref] <sup>11</sup>
12.	$\text{MAPbBr}_3$ [3D, Bulk]	6.18	-	$L_{70} \sim 14000 \text{ s}$	[Ref] <sup>12</sup>
13.	$\text{MAPbBr}_3$ [3D, Bulk]	0.38	1.72	-	[Ref] <sup>13</sup>
14.	$\text{MAPbBr}_3$ [3D, Bulk]	0.023	0.10	-	[Ref] <sup>14</sup>
15.	$\text{MAPbBr}_3$ [3D, Bulk]	-	8.22	-	[Ref] <sup>15</sup>
16.	$\text{MAPbBr}_3$ [3D, Bulk]	4.4	20.4	$L_{50} > 3 \text{ h}$ @	Our work

				<i>100 cd/m<sup>2</sup></i>	
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